	Data Sheet
<b>Central</b> <b>Semiconductor Corp.</b> 145 Adams Avenue, Hauppauge, NY 11788 USA Tel: (631) 435-1110 • Fax: (631) 435-1824	MJE170 MJE171 MJE172 PNP MJE180 MJE181 MJE182 NPN SILICON COMPLEMENTARY POWER TRANSISTOR
Manufacturers of World Class Discrete Semiconductors	JEDEC TO-126 CASE

## DESCRIPTION

The CENTRAL SEMICONDUCTOR MJE170, MJE180 series types are complementary Silicon Plastic Power Transistors designed for audio and high speed switching applications.

MAXIMUM RATINGS (T<sub>C</sub>=25°C unless otherwise noted)

Ū	SYMBOL	MJE170 MJE180	MJE171 MJE181	MJE172 MJE182	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	60	80	100	v
Collector-Emitter Voltage	VCEO	40	60	80	V
Emitter-Base Voltage	VEBO	7.0	7.0	7.0	v
Collector Current	IC IC	3.0	3.0	3.0	Α
Collector Current (Peak)	ICM	6.0	6.0	6.0	А
Base Current	IB	1.0	1.0	1.0	Α
Power Dissipation (T <sub>A</sub> =25°C)	PD	1.5	1.5	1.5	W
Power Dissipation	PD	15	15	15	W
Operating and Storage					
Junction Temperature	Tj, T <sub>stg</sub>		-65 T0 +1	50	°C
Thermal Resistance	βJA		83		°C/W
Thermal Resistance	θĴĊ		8.3		°C/W

ELECTRICAL CHARACTERISTICS ( $T_{C}=25^{\circ}C$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
ГСВО	V <sub>CB</sub> =Rated V <sub>CBO</sub>		0.1	μA
I <sub>CBO</sub>	$V_{CB}$ =Rated $V_{CB0}$ , $T_{C}$ =150°C		0.1	mA
I EBO	V <sub>BE</sub> =7.0V		0.1	μA
BVCFO	I <sub>C</sub> =10mA, (MJE170, MJE180)	40		V
BVCFO	IC=10mA, (MJE171, MJE181)	60		V
BVCEO	I <sub>C</sub> =10mA, (MJE172, MJE182)	80		V
VCE(SAT)	I <sub>C</sub> =500mÅ, I <sub>B</sub> =50mA		0.3	V
VCE(SAT)	$I_{C} = 1.5A$ , $I_{B} = 150 \text{mA}$		0.9	V
VCE(SAT)	I <sub>C</sub> =3.0A, I <sub>B</sub> =600mA		1.7	V
VBE(SAT)	$I_{C} = 1.5A$ , $I_{B} = 150 \text{mA}$		1.5	V
V <sub>BE</sub> (SAT)	$I_{C} = 3.0A$ , $I_{B} = 600 \text{mA}$		2.0	V
VBE(ON)	$V_{CE}^{2}=1.0V, I_{C}^{2}=500mA$		1.2	V
hFE	$V_{CE}=1.0V$ , $I_{C}=100mA$	50	250	
hFE	$V_{CE} = 1.0V$ , $I_{C} = 500 \text{mA}$	30		,
hFE	V <sub>CF</sub> =1.0V, I <sub>C</sub> =1.5A	12		
f <sub>T</sub>	$V_{CF}=10V$ , $I_{C}=100mA$ , f=10MHz	50		MHz
C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>F</sub> =0, f=0.1MHz (NPN)		30	рF
Cob	$V_{CB}=10V$ , $I_{E}=0$ , f=0.1MHz (PNP)		50	pF

# OUTSTANDING SUPPORT AND SUPERIOR SERVICES

#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options

#### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- · Environmental regulation compliance
- Customer specific screening
- · Up-screening capabilities

· Custom product packing

Custom bar coding for shipments

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

#### REQUESTING PRODUCT PLATING

- If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when 1. ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

### CONTACT US

#### **Corporate Headquarters & Customer Support Team**

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